# UNISONIC TECHNOLOGIES CO., LTD

MGBR10L60C **DIODE** 

# **DUAL MOS GATED** BARRIER RECTIFIER

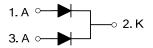
#### **DESCRIPTION**

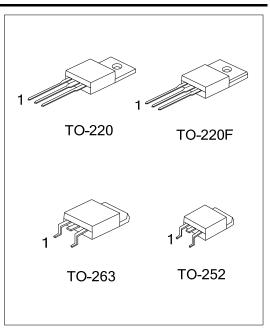
The UTC MGBR10L60C is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

#### **FEATURES**

- \* Low forward voltage drop
- \* High switching speed

#### **SYMBOL**

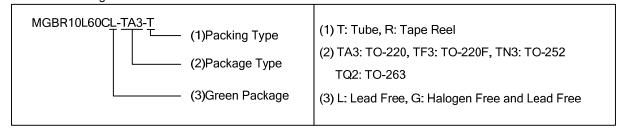




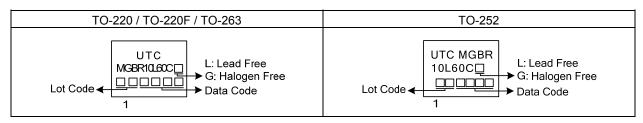
#### **ORDERING INFORMATION**

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR10L60CL-TA3-T	MGBR10L60CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR10L60CL-TF3-T	MGBR10L60CG-TF3-T	TO-220F	Α	K	Α	Tube	
MGBR10L60CL-TN3-R	MGBR10L60CG-TN3-R	TO-252	Α	K	Α	Tape Reel	
MGBR10L60CL-TQ2-T	MGBR10L60CG-TQ2-T	TO-263	Α	K	Α	Tube	
MGBR10L60CL-TQ2-R	MGBR10L60CG-TQ2-R	TO-263	Α	K	Α	Tape Reel	

Note: Pin Assignment: A: Anode K: Common Cathode



#### **MARKING**



www.unisonic.com.tw 1 of 3 MGBR10L60C

# ■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		$V_{RM}$	60	V
Working Peak Reverse Voltage		$V_{RWM}$	60	V
Peak Repetitive Reverse Voltage		$V_{RRM}$	60	V
Average Rectified Forward Current	li ci Ecg		5	Α
(Rated VR-20KHz Square Wave) – 50% duty cycle	Total	I <sub>O</sub>	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I <sub>FSM</sub>	120	Α
Peak Repetitive Reverse Surge Current (2µS-1kHz)		$I_{RRM}$	2	Α
Operating Junction Temperature		$T_J$	-65~+150	Ô
Storage Temperature		$T_{STG}$	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

# ■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	_	SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220/TO-220F		62.5	°C/W	
	TO-252	θ <sub>JA</sub>	110		
	TO-263		62.5		
Junction to Case	TO-220	θјс	2		
	TO-220F		3.31	°C/W	
	TO-252		2.5		
	TO-263		2		

# ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> =25°C, unless otherwise specified.)

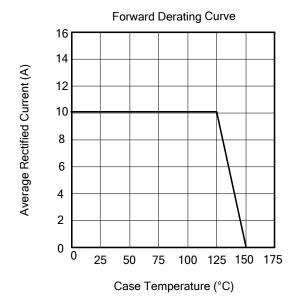
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I <sub>R</sub> =0.50mA	60			V
Forward Voltage Drop	V <sub>FM</sub>	I <sub>F</sub> =5A, T <sub>J</sub> =25°C			0.63	V
		I <sub>F</sub> =5A, T <sub>J</sub> =125°C			0.58	V
Leakage Current (Note 1)	I PM	V <sub>R</sub> =60V, T <sub>J</sub> =25°C		50	300	μΑ
		V <sub>R</sub> =60V, T <sub>J</sub> =125°C		15	50	mA

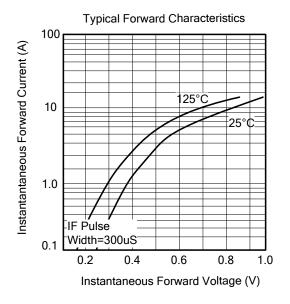
Notes: 1. Short duration pulse test used to minimize self-heating effect.

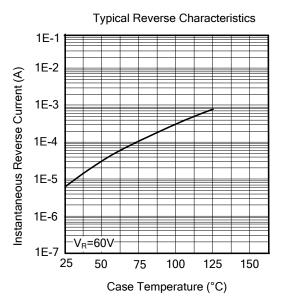
<sup>2.</sup> Thermal resistance junction to case mounted on heatsink.

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#### ■ TYPICAL CHARACTERISTICS







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